## UVA Sensor: G365T01L

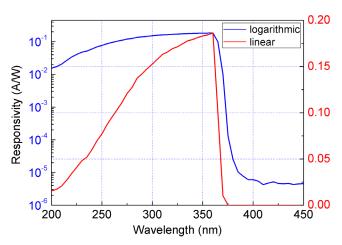
Features	Gallium nitride based material		
	Broad band UVA+UVB+UVC photodiode		
	Photovoltaic mode operation		
	TO-46 metal housing		
	Good visible blindness		
	High responsivity and low dark current		
Applications	UV LED monitoring		
	UV radiation dose measurement		
	UV Curing		



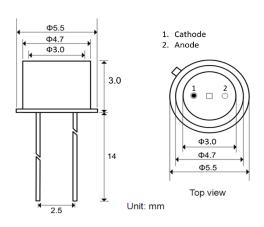
## Specifications

Parameter	Symbol	Value	Unit
Spectral characteristics (25 °C)			
Wavelength of peak responsivisity	λ <sub>max</sub>	355	nm
Peak responsivisity (at 355 nm)	R <sub>max</sub>	0.18	A/W
Spectral response range	-	220~370	nm
UV/visible rejection ratio (R <sub>max</sub> /R <sub>400 nm</sub> )	VB	>10 <sup>3</sup>	-
General characteristics (25 °C)			
Chip size	A	1	mm <sup>2</sup>
Dark current (1 V reverse bias)	l <sub>d</sub>	<50	рА
Capacitance (at 0 V and 1 MHz)	С	23	pF
Temperature coefficient	Tc	-0.1	%/°C
Maximum ratings			
Operation temperature range	T <sub>opt</sub>	-40~85	°C
Storage temperature range	T <sub>stor</sub>	-40~85	°C
Soldering temperature (3 s)	T <sub>sold</sub>	260	°C
Reverse voltage	V <sub>Rmax</sub>	10	V

## **Spectral response**



## Package dimensions



\*Caution: ESD can damage the device hence please avoid ESD.